



# RF Exposure Report

## (Part 0: SAR and PD Char Evaluation)

**FCC ID** : PU5-TP00139AM  
**Equipment** : Notebook Computer  
**Brand Name** : Lenovo  
**Model Name** : TP00139A  
**Applicant** : Wistron Corporation  
21F, No. 88, Sec. 1, Hsin Tai Wu Rd., Hsichih Dist,  
New Taipei City 221, Taiwan  
**Manufacturer** : Lenovo PC HK Limited.  
23/F, Lincoln House, Taikoo Place, 979 King's  
Road, Quarry Bay, Hong Kong, China  
**Standard** : FCC 47 CFR Part 2 (2.1093)

We, SPORTON INTERNATIONAL INC., would like to declare that the tested sample has been evaluated in accordance with the test procedures and has been in compliance with the applicable technical standards.

The test results in this report apply exclusively to the tested model / sample. Without written approval of SPORTON INTERNATIONAL INC., the test report shall not be reproduced except in full.

Approved by: Cona Huang / Deputy Manager

**Sporton International Inc. EMC & Wireless Communications Laboratory**



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## 1. Introduction

The FCC RF exposure limit is defined based on time-averaged RF exposure. The product implements Qualcomm Smart Transmit feature which controls the instantaneous transmitting power for WWAN transmitter to ensure the product in compliance with FCC RF exposure limit over a defined time window, for SAR (transmit frequency  $\leq 6\text{GHz}$ ) and power density (transmit frequency  $> 6\text{GHz}$ ). to control and manage transmitting power in real time and to ensure at all times the time-averaged RF exposure is compliant to the regulation requirement. Cannot operate without SAR and PD characterization at the device level, beforehand.

This report describes the procedures for the SAR char and PD char generation, and the parameters obtained from SAR and PD characterization (referred to as SAR char and PD char, respectively) will be used as input for Smart Transmit. Both SAR char and PD char will be entered via the Embedded File System (EFS) to enable the Smart Transmit Feature.

Terminologies in this report

$P_{\text{limit}}$	The time-averaged RF power which corresponds to SAR_design_target.
$P_{\text{max}}$	Maximum target power level
SAR_design_target:	The design target for SAR compliance. It should be less than regulatory power density limit to account for all device design related uncertainties.
SAR char	$P_{\text{limit}}$ for all the technologies/bands for all applicable DSI
PD_design_target:	The design target for PD compliance. It should be less than regulatory power density limit to account for all device design related uncertainties.
input.power.limit	For a PD characterized wireless device, the input power level at antenna port(s) for each beam corresponding to PD_design_target.
PD char	The table that contains input.power.limit fed to antenna port(s) for all supported beams.



## 2. Product Description

Product Feature & Specification	
Equipment Name	Notebook Computer
FCC ID	PU5-TP00139AM
Wireless Technology and Frequency Range	WCDMA Band II: 1850 MHz ~ 1910 MHz WCDMA Band IV: 1710 MHz ~ 1755 MHz WCDMA Band V: 824 MHz ~ 849 MHz LTE Band 2: 1850 MHz ~ 1910 MHz LTE Band 4: 1710 MHz ~ 1755 MHz LTE Band 5: 824 MHz ~ 849 MHz LTE Band 7: 2500 MHz ~ 2570 MHz LTE Band 12: 699 MHz ~ 716 MHz LTE Band 13: 777 MHz ~ 787 MHz LTE Band 14: 788 MHz ~ 798 MHz LTE Band 17: 704 MHz ~ 716 MHz LTE Band 25: 1850 MHz ~ 1915 MHz LTE Band 26: 814 MHz ~ 849 MHz LTE Band 30: 2305 MHz ~ 2315 MHz LTE Band 38: 2570 MHz ~ 2620 MHz LTE Band 41: 2496 MHz ~ 2690 MHz LTE Band 42: 3550 MHz ~ 3600 MHz LTE Band 48: 3550 MHz ~ 3700 MHz LTE Band 66: 1710 MHz ~ 1780 MHz LTE Band 71: 663 MHz ~ 698 MHz 5G NR n2 : 1850 MHz ~ 1910 MHz 5G NR n5 : 824 MHz ~ 849 MHz 5G NR n7 : 2500 MHz ~ 2570 MHz 5G NR n12 : 699 MHz ~ 716 MHz 5G NR n25 : 1850 MHz ~ 1915 MHz 5G NR n38 : 2570 MHz ~ 2620 MHz 5G NR n41 : 2496 MHz ~ 2690 MHz 5G NR n66 : 1710 MHz ~ 1780 MHz 5G NR n71 : 663 MHz ~ 698 MHz 5G NR n77: 3700 MHz ~ 3980 MHz 5G NR n260 : 37 GHz~40 GHz 5G NR n261 : 27.5 GHz~28.35 GHz WLAN 2.4 GHz Band: 2400 MHz ~ 2483.5 MHz WLAN 5.2 GHz Band: 5150 MHz ~ 5250 MHz WLAN 5.3 GHz Band: 5250 MHz ~ 5350 MHz WLAN 5.6 GHz Band: 5470 MHz ~ 5725 MHz WLAN 5.8 GHz Band: 5725 MHz ~ 5850 MHz WLAN 6E: 5925 MHz ~ 6425 MHz, 6425 MHz ~ 6525 MHz, 6525 MHz ~ 6875 MHz, 6875 MHz ~ 7125 MHz Bluetooth: 2400 MHz ~ 2483.5 MHz
Mode	RMC 12.2Kbps HSDPA HSUPA DC-HSDPA LTE: QPSK, 16QAM, 64QAM, 256QAM 5G NR: DFT-s-OFDM/CP-OFDM, Pi/2 BPSK/QPSK/16QAM/64QAM/256QAM WLAN: 802.11a/b/g/n/ac/ax HT20/HT40/VHT20/VHT40/VHT80/VHT160/HE20/HE40/HE80/HE160 Bluetooth BR/EDR/LE



### 3. SAR Characterization

SAR char must be generated to cover all radio configurations and usage scenarios that the wireless device supports for operating at 6 GHz or below. It will then be used as input for Smart Transmit to control and manage RF exposure for  $f < 6$  GHz.

#### 3.1 SAR design target and uncertainty

##### SAR design target

The detail SAR design target relate to each exposure conditions pls refer to operation description

1g SAR design target	0.95 W/kg
Uncertainty	1 dB

To account for total uncertainty, SAR\_design\_target should be determined as:

$$SAR_{design\_target} < SAR_{regulatory\_limit} \times 10^{\frac{-total\ uncertainty}{10}}$$



### 3.2 SAR Char Table

SAR char must be generated to cover all radio configurations and usage scenarios that the wireless device supports for operating at 6 GHz or below. It will then be used as input for Smart Transmit to control and manage RF exposure for f < 6 GHz

**<P<sub>limit</sub> for supported technologies and bands (P<sub>limit</sub> in EFS file)>**

#### Ant 0

Band	Antenna	Duty cycle	P <sub>limit</sub> (dBm)	P <sub>Max</sub> * (dBm)
			Time-average power	Time-average power
WCDMA II	0	100.00%	17.50	23.50
WCDMA IV	0	100.00%	17.50	23.50
WCDMA V	0	100.00%	20.80	23.50
LTE B7	0	100.00%	14.50	23.00
LTE B12/17	0	100.00%	20.80	23.50
LTE B13	0	100.00%	20.70	23.50
LTE B14	0	100.00%	20.40	23.50
LTE B25/2	0	100.00%	17.50	23.00
LTE B26/5	0	100.00%	18.90	23.50
LTE B30	0	100.00%	16.00	22.00
LTE B38/41**	0	63.30%	15.50	21.00
LTE B41_HPUE**	0	43.30%		22.40
LTE B66/4	0	100.00%	17.40	23.00
LTE B71	0	100.00%	21.60	23.50
FR1 n2	0	100.00%	18.10	23.00
FR1 n5	0	100.00%	19.40	23.00
FR1 n12	0	100.00%	22.00	23.00
FR1 n66	0	100.00%	17.70	23.00
FR1 n71	0	100.00%	20.70	23.00

**Ant 2**

Band	Antenna	Duty cycle	P <sub>limit</sub> (dBm) Time-average power	P <sub>Max</sub> * (dBm) Time-average power
LTE B2	2	100.00%	16.30	23.00
LTE B7	2	100.00%	17.50	23.00
LTE B42**	2	63.30%	15.40	19.00
LTE B48**	2	63.30%	15.60	19.00
LTE B66	2	100.00%	17.30	23.00
FR1 n7	2	100.00%	16.40	23.00
FR1 n25/2	2	100.00%	15.40	23.00
FR1 n41/38	2	100.00%	16.20	23.00
FR1 n66	2	100.00%	20.20	23.00
FR1 n77	2	100.00%	16.20	23.00
FR1 n77_HPUE**	2	50.00%		23.00

\*P<sub>max</sub> is used for RF tune up procedure. The maximum allowed output power is equal to P<sub>max</sub> + 1dB uncertainty.

\*\*All P<sub>limit</sub> power levels entered in the Table correspond to average power levels after accounting for duty cycle in the case TDD modulation schemes (for e.g., GSM & LTE TDD & NR TDD).

The max allowed output power is the P<sub>limit</sub> + device uncertainty, and if P<sub>limit</sub> is higher than P<sub>max</sub>, the device output power will be P<sub>max</sub> instead.



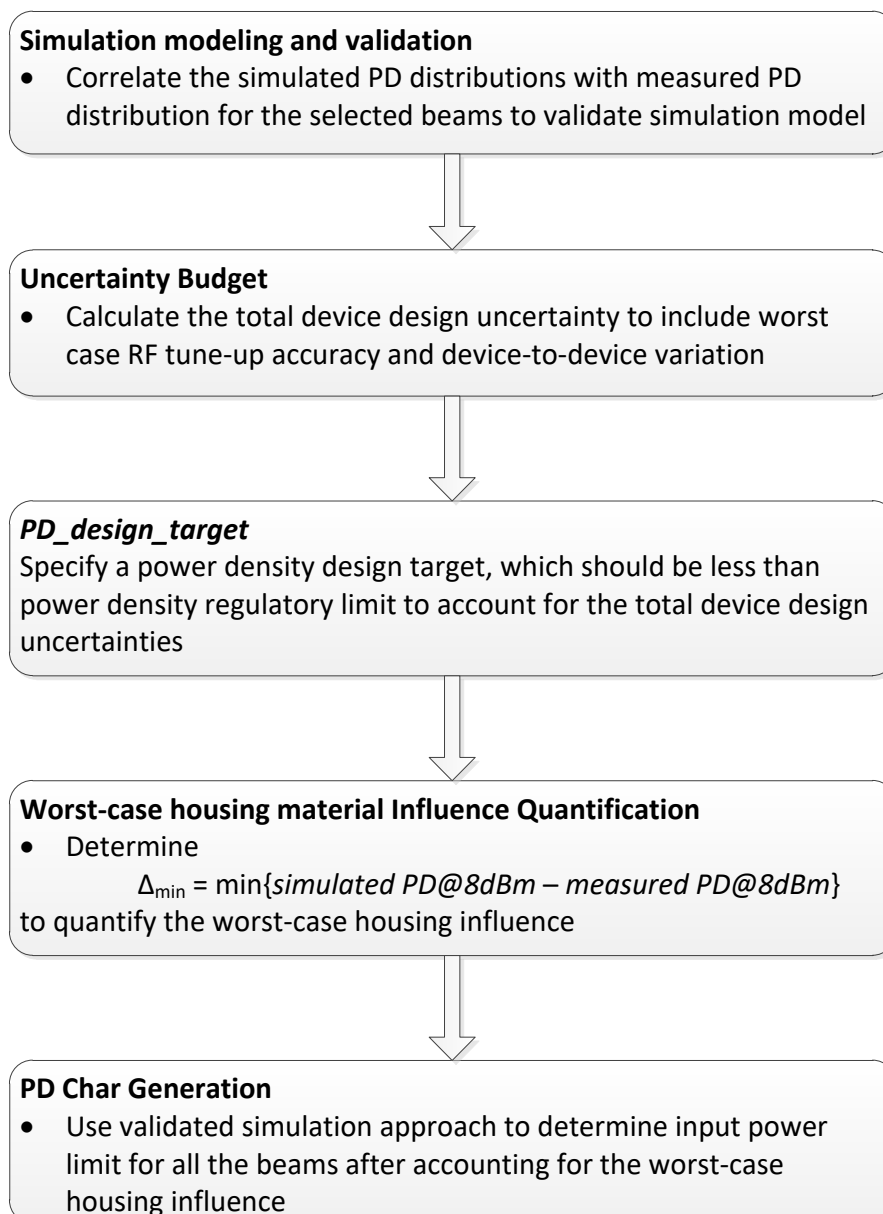
## 4. Power Density Characterization

The device with 5G mmW NR typically supports many beams and contains multiple mmW antenna arrays installed at different locations to achieve good coverage in the field. The power density (PD) measurement is a time-consuming test, and it is not practical to measure the power density for all the beams on all the surfaces of the device, thus a hybrid approach using electromagnetic (EM) simulation in combination with measurement is recommended for PD char generation

### 4.1 PD Char Table

The mmW device supports total N beams, where M out of N are single beams and the rest of (N-M) are beam pairs (where 2 single beams are excited at the same time).

The following figure outlines the PD char process.





**4.2 Codebook for all beams**

All the beams that the device supports are specified in the pre-defined codebook, and the codebook is device design specific and generated after evaluating radiation coverage from this particular device. In the field, a smartphone manages the beam selection and utilization based on this pre-defined codebook that is loaded and stored in the device.

Band	Module	Beam ID 2	Beam ID 1
n260	AiP_0		0
			3
			6
			7
			8
			9
			18
			19
			20
			27
			28
			29
			30
			31
			42
			43
			44
			45
			128
			131
			134
			135
			136
			137
			146
			147
			148
			155
			156
			157
			158
			159
			170
			171
			172
			173
			128
			131
			134
			135
			136
			137
	146		
	147		
	148		
	155		
	156		
	157		
	158		
	159		
	170		
	170		



		171	43
		172	44
		173	45
			1
			4
			10
			11
			12
			13
			21
			22
			23
			32
			33
			34
			35
			36
			46
			47
			48
			49
		129	
		132	
		138	
		139	
		140	
		141	
		149	
		150	
		151	
		160	
		161	
		162	
		163	
		164	
		174	
		175	
		176	
		177	
		129	1
		132	4
		138	10
		139	11
		140	12
		141	13
		149	21
		150	22
		151	23
		160	32
		161	33
		162	34
		163	35
		164	36
		174	46
		175	47
		176	48
		177	49
n260	AiP_1		2
n260	AiP_2		5



		14
		15
		16
		17
		24
		25
		26
		37
		38
		39
		40
		41
		50
		51
		52
		53
	130	
	133	
	142	
	143	
	144	
	145	
	152	
	153	
	154	
	165	
	166	
	167	
	168	
	169	
	178	
	179	
	180	
	181	
	130	2
	133	5
	142	14
	143	15
	144	16
	145	17
	152	24
	153	25
	154	26
	165	37
	166	38
	167	39
	168	40
	169	41
	178	50
	179	51
	180	52
	181	53



Band	Module	Beam ID 2	Beam ID 1
n261	AiP_0		0
			3
			6
			7
			8
			9
			18
			19
			20
			27
			28
			29
			30
			31
			42
			43
			44
			45
			128
			131
			134
			135
			136
			137
			146
			147
			148
			155
			156
			157
			158
			159
			170
			171
			172
			173
			128
			131
			134
			135
			136
			137
			146
			147
			148
	155		
	156		
	157		
	158		
	159		
	170		
	171		
	172		
	173		
	0		
	3		
	6		
	7		
	8		
	9		
	18		
	19		
	20		
	27		
	28		
	29		
	30		
	31		
	42		
	43		
	44		
	45		



n261	AiP_1		1		
			4		
			10		
			11		
			12		
			13		
			21		
			22		
			23		
			32		
			33		
			34		
			35		
			36		
			46		
			47		
			48		
			49		
			129		
			132		
			138		
			139		
			140		
			141		
			149		
			150		
			151		
			160		
			161		
			162		
			163		
			164		
			174		
			175		
			176		
			177		
			129		1
			132		4
			138		10
			139		11
			140		12
			141		13
			149		21
			150		22
			151		23
			160		32
			161		33
			162		34
			163		35
	164		36		
	174		46		
	175		47		
	176		48		
	177		49		
n261	AiP_2		2		
			5		



		14
		15
		16
		17
		24
		25
		26
		37
		38
		39
		40
		41
		50
		51
		52
		53
	130	
	133	
	142	
	143	
	144	
	145	
	152	
	153	
	154	
	165	
	166	
	167	
	168	
	169	
	178	
	179	
	180	
	181	
	130	2
	133	5
	142	14
	143	15
	144	16
	145	17
	152	24
	153	25
	154	26
	165	37
	166	38
	167	39
	168	40
	169	41
	178	50
	179	51
	180	52
	181	53

**4.3 PD design target determination**

To account for total uncertainty, PD\_design\_target should meet the criteria:

$$PD\_design\_target < PD_{regulatory\_limit} \times 10^{\frac{-totaluncertainty}{10}}$$

For this EUT, the PD design target and the uncertainty value are listed below

n260/261	PD design target	Antenna Module	W/m <sup>2</sup>
		Antenna Module 0	5.55
		Antenna Module 1	3.08
		Antenna Module 2	5.55

Item	Uncertainty dB (k=2)
Total uncertainty	2.1



4.4 Exposure positions for PD evaluation

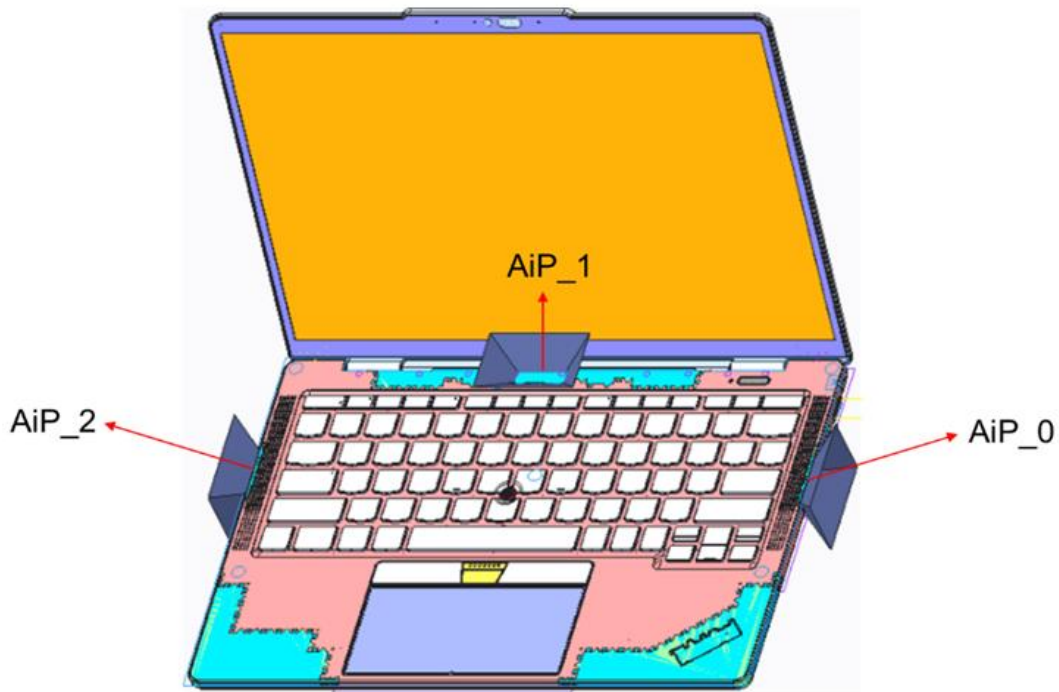


Figure 2 (b) AiP Location (with AiP Sketch).

Evaluation positions

Antenna Module	Bottom of Laptop 2mm
Antenna module 0 / 1 / 2	v



4.5 Simulation and modeling validation

Power density simulations of all beams and surfaces were performed by the manufacturer. Details of these simulations and modeling validation can be found in the Power Density Simulation Report. Following Table includes a summary of the validation results to support worst-case housing influence quantification in power density characterization for this model With an input power of 6 dBm for n261 and n260 band, PD measurements are conducted for at least one single beam per antenna type and per antenna module (0,1) on worst-surface(s) . PD measurements are performed at mid channel of each mmW band and with CW modulation. PD value will be used to determine worst-case housing influence for conservative assessment

Table with 10 columns: Band, Antenna Module, Beam ID 1, Beam ID 2, Frequency (GHz), Exposure Surface, Test Separation (mm), Measured results Savg tot 4cm^2 (W/m2), Simulated Pd (W/m^2), averaged over 4 cm2, Delta= Sim. - Meas. (dB). Rows include data for bands n260 and n261 across various antenna modules and beam IDs.

## 4.6 PD Char

### 4.6.1 Simulated input power limit for single beams

Perform simulation at low, mid and high channel for each mmW band supported, with a given input power per active port, *sim.input.power.per.active.port* (6 dBm for this product):

1. Obtain  $PD_{surface}$  value (the worst PD among all identified surfaces of the device) at all three channels for all single beams (1~M) specified in *codebook\_sim*.
2. Adjust input power to determine a scaling factor at all three channels by:

$$s(i)_{low\_or\_mid\_high} = \frac{PD\ design\ target}{sim.PD_{surface}(i)}, i = 1, 2, \dots M \quad (4)$$

3. Determine the worst-case scaling factor among low, mid and high channels:

$$s(i) = \min\{s_{low}(i), s_{mid}(i), s_{high}(i)\}, i = 1, 2, \dots M \quad (5)$$

Note: This scaling factor applies to the input power at each antenna port

4. Determine the simulated input power limit, *sim.powerlimit*, for single beam *i* by:

$$sim.\ powerlimit.(i)dBm = 10 * \log(s(i)) + sim.input.power.per.active.port, i = 1, 2, \dots M \quad (6)$$

**4.6.2 Simulated input power limit for beam pairs**

The relative phase between single beams of a beam pair is swept to find the worst case PD for beam-pairs operation, and PD simulation data has taken this into consideration for beam-pair operations take consideration of the variation relative phase was reported

For beam pair, extract the E-fields and H-fields from the corresponding single beams at and high channel for each supported band and for all identified surfaces of the device.

For a given beam pair containing *beam\_a* and *beam\_b* with relative phase  $\phi$  and for a given channel, determine the worst-case  $\phi_{worstcase}$  which results in the highest total PD ( $\phi$ ) among all identified surfaces for this beam pair at this channel. When  $\phi_{worstcase}$  is determined for all three channels, obtain the scaling factor given by the below equation for low, mid and high channels:

$$s(i)_{low\_or\_mid\_high} = \frac{PD\ design\ target}{total.PD(\phi(i)_{worstcase})}, i = M+1, M+2, \dots N \quad (8)$$

The  $\phi_{worstcase}$  varies with channel and beam pair, the lowest scaling factor among all three channels,  $s(i)$ , is determined for the beam pair  $i$ :

$$s(i) = \min\{s_{low}(i), s_{mid}(i), s_{high}(i)\}, i = M+1, M+2, \dots N \quad (9)$$

The simulated input power limit, *sim.powerlimit*, for beam pair  $i$  can be determined by

$$sim.powerlimit(i)dBm = 10 * \log(s(i)) + sim.input.power.per.active.port, i = M+1, M+2, \dots N \quad (10)$$

### 4.7 PD Char

This section describes the PD char generation that complies with the *PD\_design\_target* and is in compliance with the regulatory power density limit.

#### 4.7.1 PD char generation

Ideally, if there is no uncertainty associated with hardware as described in Section 4.4, after accounting for the housing influence ( $\Delta_{min}$ ), *input.power.limit(i)*, for beam *i* can be obtained:

$$input.power.limit(i) = 6\text{ dBm} + 10 * \log(s(i)) + \Delta_{min}, i \in \text{all beams} \quad (11)$$

If simulation overestimates the housing influence, then  $\Delta_{min}$  (= minimum {simulated PD – measured PD}) is negative, which means that the measured PD would be higher than the simulated PD. The input power to antenna elements determined via simulation must be decreased for compliance.

Similarly, if simulation underestimates loss, then  $\Delta_{min}$  is positive (measured PD would be lower than the simulated value). Input power to antenna elements determined via simulation can be increased and still be PD compliant.

In reality, the hardware design has uncertainty which must be properly considered in equation (11). In Section 4.7, the TxAGC uncertainty at reference power level (6dBm in report) is embedded in the process of  $\Delta_{min}$  determination and should be removed to avoid double counting this uncertainty.

If -TxAGC uncertainty at reference power level <  $\Delta_{min}$  < TxAGC uncertainty at reference power level,

$$Input.power.limit(i) = sim.powerlimit(i), i = 1,2,...,N \quad (12)$$

else if  $\Delta_{min}$  < -TxAGC uncertainty at reference power level,

$$Input.power.limit(i) = sim.powerlimit(i) + (\Delta_{min} + TxAGC\ uncertainty), i = 1,2,...,N \quad (13)$$

else if  $\Delta_{min}$  > TxAGC uncertainty at reference power level,

$$Input.power.limit(i) = sim.powerlimit(i) + (\Delta_{min} - TxAGC\ uncertainty), i = 1,2,...,N \quad (14)$$

The input power limit is derived and listed in the table below

Band	Antenna	Beam ID	Delta_min (dB)	TxAGC uncertainty (dB)	Input.power.limit (dBm)=
n260	AiP_0	Beam ID 1	7.775	0.5	$6 + 10 * \log(s(i)) + 7.275$
		Beam ID 2	7.116	0.5	$6 + 10 * \log(s(i)) + 6.616$
	AiP_1	Beam ID 1	6.914	0.5	$6 + 10 * \log(s(i)) + 6.414$
		Beam ID 2	4.918	0.5	$6 + 10 * \log(s(i)) + 4.418$
	AiP_2	Beam ID 1	6.279	0.5	$6 + 10 * \log(s(i)) + 5.779$
		Beam ID 2	4.331	0.5	$6 + 10 * \log(s(i)) + 3.831$
n261	AiP_0	Beam ID 1	3.429	0.5	$6 + 10 * \log(s(i)) + 2.929$
		Beam ID 2	3.53	0.5	$6 + 10 * \log(s(i)) + 3.03$
	AiP_1	Beam ID 1	3.961	0.5	$6 + 10 * \log(s(i)) + 3.461$
		Beam ID 2	-2.128	0.5	$6 + 10 * \log(s(i)) + 0.287$
	AiP_2	Beam ID 1	3.087	0.5	$6 + 10 * \log(s(i)) + 2.587$
		Beam ID 2	0.077	0.5	$6 + 10 * \log(s(i)) + 0.077$



**4.7.2 PD char Table**

Combining the information in previous sections, PD char is derived and listed below

Band	Module	Beam ID 2	Beam ID 1	Input power limit(dBm)	
n260	AiP_0		0	17.84	
			3	18.44	
			6	16.79	
			7	15.13	
			8	14.48	
			9	15.34	
			18	16.23	
			19	14.99	
			20	15.10	
			27	13.30	
			28	13.26	
			29	12.70	
			30	12.45	
			31	13.56	
			42	13.28	
			43	13.14	
			44	12.56	
			45	12.64	
			128		18.63
			131		18.45
			134		15.32
			135		15.51
			136		15.01
			137		14.85
			146		16.13
			147		15.10
			148		15.94
			155		12.36
			156		12.50
			157		12.52
			158		12.09
			159		12.54
			170		12.60
			171		12.08
			172		12.62
			173		12.21
			128	0	14.01
			131	3	14.07
			134	6	11.51
			135	7	11.26
			136	8	11.07
			137	9	11.06
	146	18	12.52		
	147	19	10.97		
	148	20	11.59		
	155	27	8.89		
	156	28	8.54		
	157	29	8.37		
	158	30	8.90		
	159	31	8.99		
	170	42	9.20		



		171	43	8.56		
		172	44	9.11		
		173	45	8.37		
n260	AiP_1		1	19.50		
			4	16.39		
			10	14.63		
			11	13.36		
			12	15.99		
			13	12.41		
			21	13.88		
			22	14.70		
			23	16.25		
			32	14.70		
			33	10.03		
			34	12.55		
			35	14.99		
			36	13.15		
			46	13.27		
			47	12.28		
			48	11.59		
			49	14.16		
				129		15.52
				132		18.85
				138		15.77
				139		14.40
				140		14.95
				141		13.78
				149		12.25
				150		12.70
				151		12.33
				160		13.00
				161		10.40
				162		11.27
				163		12.96
				164		9.75
				174		11.53
				175		11.83
				176		11.51
				177		11.11
				129	1	14.70
				132	4	12.81
				138	10	11.23
				139	11	10.14
				140	12	12.36
				141	13	8.28
				149	21	9.70
				150	22	9.38
				151	23	12.36
				160	32	10.75
				161	33	5.85
				162	34	7.43
		163	35	11.47		
		164	36	7.55		
		174	46	8.58		
		175	47	8.80		
		176	48	7.42		



		177	49	9.33
			2	18.02
			5	19.05
			14	14.09
			15	13.22
			16	14.06
			17	13.63
			24	13.34
			25	15.02
			26	14.14
			37	12.28
			38	11.35
			39	11.50
			40	11.87
			41	11.67
			50	11.36
			51	11.15
			52	11.55
			53	12.15
		130		15.37
		133		15.84
		142		12.40
		143		11.98
		144		13.33
		145		11.87
		152		11.69
		153		12.17
		154		13.06
n260	AiP_2	165		9.95
		166		9.36
		167		9.44
		168		9.75
		169		9.68
		178		9.73
		179		9.83
		180		9.51
		181		10.23
		130	2	13.28
		133	5	13.98
		142	14	10.55
		143	15	9.35
		144	16	11.17
		145	17	9.22
		152	24	9.93
		153	25	10.21
		154	26	10.02
		165	37	7.66
		166	38	7.08
		167	39	7.56
		168	40	6.92
		169	41	7.52
		178	50	7.38
		179	51	7.80
		180	52	7.20
		181	53	7.86





Band	Module	Beam ID 2	Beam ID 1	Input power limit(dBm)	
n261	AiP_0		0	16.64	
			3	15.10	
			6	14.41	
			7	11.64	
			8	13.49	
			9	13.30	
			18	13.56	
			19	11.93	
			20	13.77	
			27	10.86	
			28	10.42	
			29	9.10	
			30	10.31	
			31	10.88	
			42	10.09	
			43	9.84	
			44	9.55	
			45	10.96	
			128		15.61
			131		15.47
			134		13.59
			135		14.74
			136		11.22
			137		13.15
			146		14.22
			147		12.39
			148		13.48
			155		11.30
			156		11.59
			157		9.82
			158		9.07
			159		10.61
			170		10.80
			171		10.98
			172		9.21
			173		10.40
			128	0	11.41
			131	3	10.91
			134	6	10.06
			135	7	9.93
			136	8	7.61
			137	9	9.40
			146	18	9.95
			147	19	8.30
			148	20	9.58
	155	27	8.06		
	156	28	7.01		
	157	29	6.13		
	158	30	5.51		
	159	31	7.31		
	170	42	7.25		
	171	43	6.64		
	172	44	5.86		
	173	45	6.45		



n261	AiP_1		1	12.36	
			4	12.32	
			10	9.31	
			11	9.40	
			12	9.29	
			13	9.94	
			21	10.13	
			22	8.28	
			23	10.60	
			32	6.92	
			33	6.80	
			34	5.99	
			35	7.69	
			36	7.42	
			46	6.98	
			47	6.33	
			48	6.28	
			49	8.83	
			129	6.56	
			132	6.92	
			138	4.64	
			139	4.33	
			140	4.19	
			141	4.45	
			149	6.35	
			150	3.98	
			151	2.87	
			160	2.35	
			161	3.47	
			162	1.58	
			163	0.88	
			164	1.46	
			174	2.75	
			175	1.79	
			176	0.92	
			177	0.90	
			129	1	7.76
			132	4	7.56
			138	10	5.83
			139	11	5.41
			140	12	5.48
			141	13	7.35
			149	21	6.71
			150	22	3.99
			151	23	4.91
			160	32	3.90
			161	33	3.51
			162	34	3.08
			163	35	3.35
	164	36	3.61		
	174	46	3.74		
	175	47	2.34		
	176	48	2.36		
	177	49	3.20		
n261	AiP_2		2	15.03	
			5	15.03	



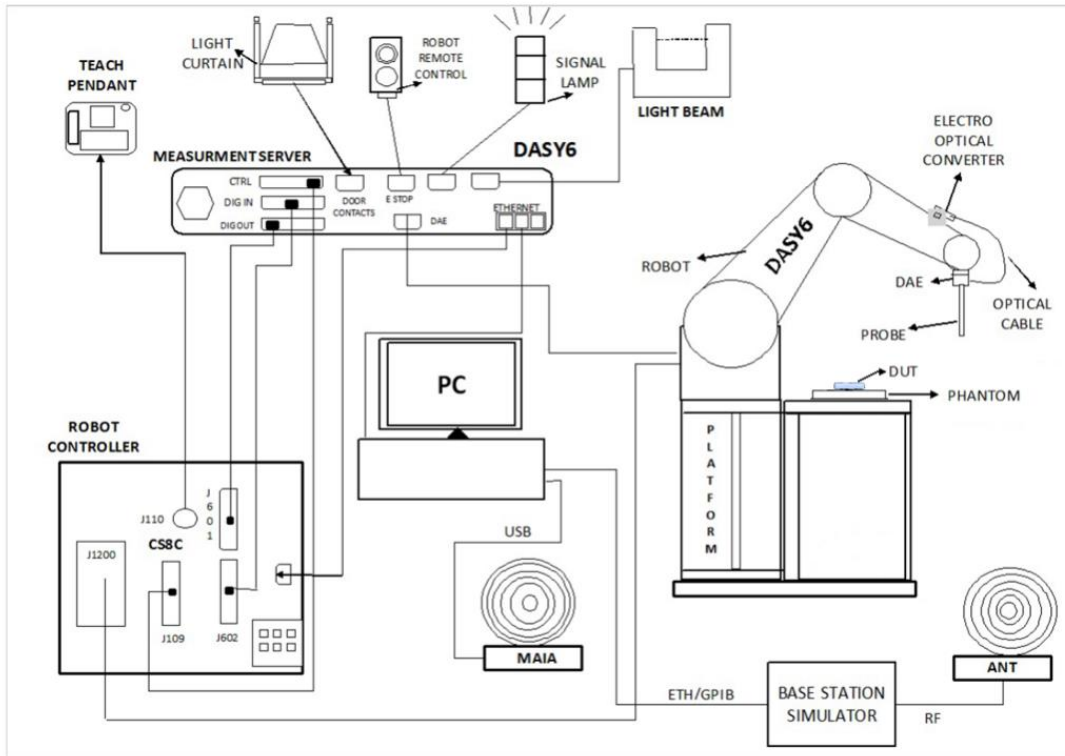
		14	12.21
		15	12.17
		16	11.95
		17	12.81
		24	13.00
		25	11.23
		26	13.50
		37	9.67
		38	9.73
		39	8.84
		40	10.45
		41	10.37
		50	9.73
		51	9.04
		52	9.23
		53	11.30
	130		11.59
	133		11.72
	142		9.68
	143		9.20
	144		9.08
	145		9.37
	152		11.12
	153		8.80
	154		7.90
	165		7.39
	166		8.37
	167		6.61
	168		5.72
	169		6.49
	178		7.77
	179		6.82
	180		5.91
	181		5.93
	130	2	10.56
	133	5	10.44
	142	14	8.71
	143	15	8.19
	144	16	8.36
	145	17	10.10
	152	24	9.59
	153	25	6.95
	154	26	7.86
	165	37	6.82
	166	38	6.07
	167	39	5.86
	168	40	6.05
	169	41	6.49
	178	50	6.22
	179	51	5.22
	180	52	5.25
	181	53	6.07

## 5. PD Test Setup

### 5.1 PD Test – System Setup

The system to be used for the near field power density measurement

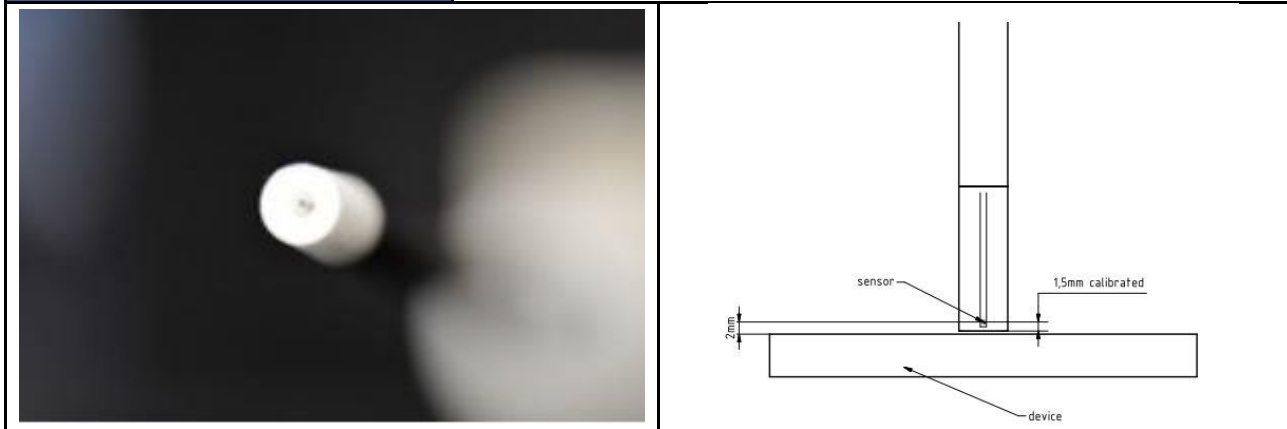
- SPEAG DASY6 system
  - SPEAG cDASY6 5G module software
  - EUmmWVx probe
- 5G Phantom cover



**5.2 EUmmWave Probe / E-Field 5G Probe**

The probe design allows measurements at distances as small as 2 mm from the sensors to the surface of the device under test (DUT). The typical sensor to probe tip distance is 1.5 mm.

<b>Frequency</b>	750 MHz – 110 GHz
<b>Probe Overall Length</b>	320 mm
<b>Probe Body Diameter</b>	8.0 mm
<b>Tip Length</b>	23.0 mm
<b>Tip Diameter</b>	8.0 mm
<b>Probe's two dipoles length</b>	0.9 mm – Diode loaded
<b>Dynamic Range</b>	< 20 V/m - 10000 V/m with PRE-10 (min < 50 V/m - 3000 V/m)
<b>Position Precision</b>	< 0.2 mm
<b>Distance between diode sensors and probe's tip</b>	1.5 mm
<b>Minimum Mechanical separation between probe tip and a Surface</b>	0.5 mm
<b>Applications</b>	E-field measurements of 5G devices and other mm-wave transmitters operating above 10GHz in < 2 mm distance from device (free-space) Power density, H-field and far-field analysis using total field reconstruction.
<b>Compatibility</b>	cDASY6 + 5G-Module SW1.0 and higher



**5.3 Data Acquisition Electronics (DAE)**

The data acquisition electronics (DAE) consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the measurement server is accomplished through an optical downlink for data and status information as well as an optical uplink for commands and the clock.

The input impedance of the DAE is 200 MOhm; the inputs are symmetrical and floating. Common mode rejection is above 80 dB.



**5.4 Scan configuration**

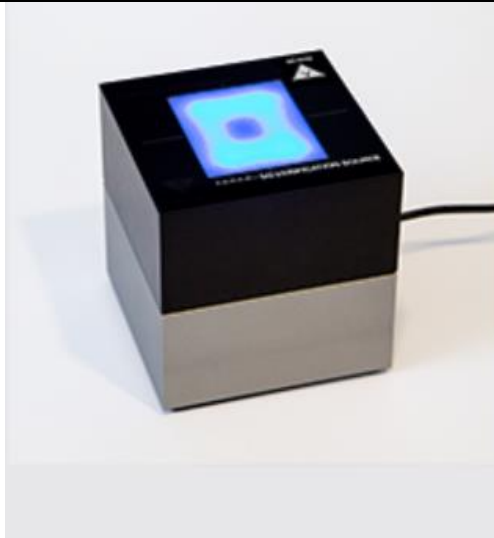
Fine-resolution scans on 2 different planes are performed to reconstruct the E- and H-fields as well as the power density; the z-distance between the 2 planes is set to  $\lambda/4$ .

The (x, y) grid step is also set  $\lambda/4$ , the grid extent is set to sufficiently large to identify the field pattern and the peak.

**5.5 System Verification Source**

The System Verification sources at 30 GHz and above comprise horn-antennas and very stable signal generators.

<b>Model</b>	Ka-band horn antenna
<b>Calibrated frequency:</b>	30 GHz at 10mm from the case surface
<b>Frequency accuracy</b>	$\pm 100$ MHz
<b>E-field polarization</b>	linear
<b>Harmonics</b>	-20 dBc
<b>Total radiated power</b>	14 dBm
<b>Power stability</b>	0.05 dB
<b>Power consumption</b>	5 W
<b>Size</b>	00 x 100 x 100 mm
<b>Weight</b>	1 kg

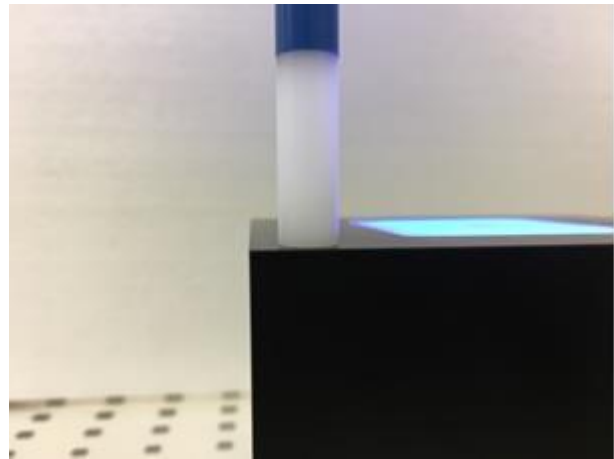
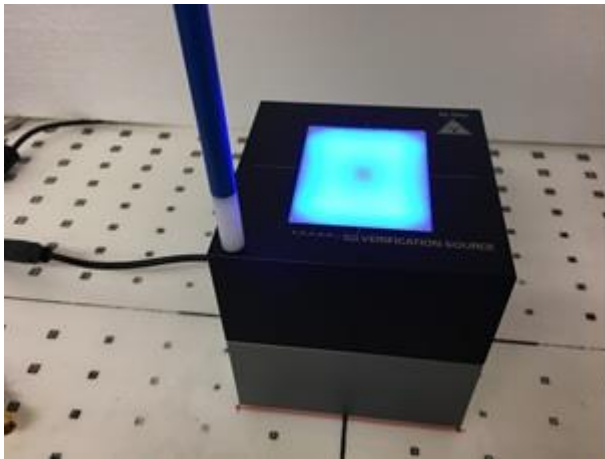


### 5.6 Power Density System Verification

The system performance check verifies that the system operates within its specifications. The EUT is replaced by a calibrated source, the same spatial resolution, measurement region and the test separation used in the calibration was applied to system check. Through visual inspection into the measured power density distribution, both spatially (shape) and numerically (level) have no noticeable difference. The measured results should be within 0.66B of the calibrated targets.

Frequency [GHz]	Grid step	Grid extent X/Y [mm]	Measurement points
10	0.25 ( $\frac{\lambda}{4}$ )	120/120	16 × 16
30	0.25 ( $\frac{\lambda}{4}$ )	60/60	24 × 24
60	0.25 ( $\frac{\lambda}{4}$ )	32.5/32.5	26 × 26
90	0.25 ( $\frac{\lambda}{4}$ )	30/30	36 × 36

Settings for measurement of verification sources



Verification Setup photo

### 5.7 System Verification Results

Frequency (GHz)	5G Verification Source	Probe S/N	DAE S/N	Distance (mm)	Measured 4 cm <sup>2</sup> (W/m <sup>2</sup> )	Targeted 4 cm <sup>2</sup> (W/m <sup>2</sup> )	Deviation (dB)	Date
30G	30GHz_1007	9441	778	10	33.1	35.8	-0.34	2021/12/29
30G	30GHz_1007	9441	778	10	32.6	35.8	-0.41	2022/1/31
30G	30GHz_1007	9441	778	10	32.8	35.8	-0.38	2022/3/10



## 6. Uncertainty Assessment

The budget is valid for evaluation distances  $> \lambda/2\pi$ . For specific tests and configurations, the Uncertainty could be considerably smaller.

Preliminary Module mmWave Uncertainty Budget Evaluation Distances to the Antennas $> \lambda / 2\pi$						
Error Description	Uncertainty Value ( $\pm$ dB)	Probability	Divisor	(Ci)	Standard Uncertainty ( $\pm$ dB)	(Vi) Veff
<b>Measurement System</b>						
Probe Calibration	0.49	N	1	1	0.49	$\infty$
Hemispherical Isotropy	0.50	R	1.732	1	0.29	$\infty$
Linearity	0.20	R	1.732	0	0.12	$\infty$
System Detection Limits	0.04	R	1.732	1	0.02	$\infty$
Modulation Response	0.40	R	1.732	1	0.23	$\infty$
Readout Electronics	0.03	N	1	1	0.03	$\infty$
Response Time	0.00	R	1.732	1	0.00	$\infty$
Integration Time	0.00	R	1.732	1	0.00	$\infty$
RF Ambient Noise	0.2	R	1.732	1	0.12	$\infty$
RF Ambient Reflections	0.21	R	1.732	1	0.12	$\infty$
Probe Positioner	0.04	R	1.732	1	0.02	$\infty$
Probe Positioning	0.30	R	1.732	1	0.17	$\infty$
Savg Reconstruction	0.60	R	1.732	1	0.35	$\infty$
<b>Test Sample Related</b>						
Power Drift	0.2	R	1.732	1	0.12	$\infty$
Input Power	0	N	1	0	0.00	$\infty$
Combined Std. Uncertainty					0.76 dB	$\infty$
Coverage Factor for 95 %					K=2	
Expanded STD Uncertainty					1.52 dB	